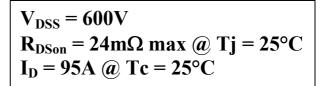
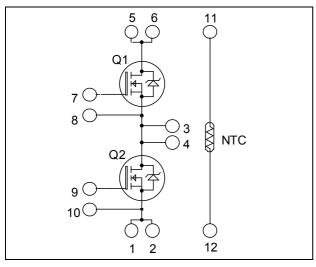
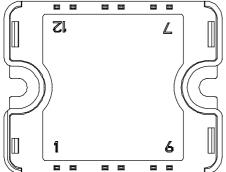


Phase leg Super Junction MOSFET Power Module







Pins 1/2; 3/4; 5/6 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

• COOLMOS

Power Semiconductors

- Ultra low R_{DSon}
- Low Miller capacitance
- Ultra low gate charge
- Avalanche energy rated
- Very rugged
- Very low stray inductance
 - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		600	V
Ţ	Continuous Drain Current	$T_c = 25^{\circ}C$	95	
I_D	Continuous Diam Current	$T_c = 80$ °C	70	A
I_{DM}	Pulsed Drain current		260	
V_{GS}	Gate - Source Voltage		±20	V
R_{DSon}	Drain - Source ON Resistance		24	mΩ
P_{D}	Maximum Power Dissipation $T_c = 25^{\circ}C$		462	W
I_{AR}	Avalanche current (repetitive and non repetitive)		15	A
E_{AR}	Repetitive Avalanche Energy		3	mJ
E_{AS}	Single Pulse Avalanche Energy		1900	1113

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 600V$	$T_j = 25$ °C			350	μА
		$V_{GS} = 0V, V_{DS} = 600V$	$T_{j} = 125^{\circ}C$			600	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 47.5A$				24	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$		2.1	3	3.9	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$				200	nA

Dynamic Characteristics

•	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V ; V_{DS} = 25V$		14.4		nF
C_{oss}	Output Capacitance	f = 1MHz		17		111
Q_{g}	Total gate Charge	$V_{GS} = 10V$		300		
Q_{gs}	Gate – Source Charge	$V_{\text{Bus}} = 300V$		68		nC
Q_{gd}	Gate – Drain Charge	$I_D = 95A$		102		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)		21		
$T_{\rm r}$	Rise Time	$V_{GS} = 10V$		30		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 400V$ $I_{\text{D}} = 95A$		100		ns
T_{f}	Fall Time	$R_G = 2.5\Omega$		45		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 10V$; $V_{Bus} = 400V$		1350		μJ
E_{off}	Turn-off Switching Energy	$I_D = 95A$; $R_G = 2.5\Omega$		1040		μυ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		2200		T
E_{off}	Turn-off Switching Energy	$V_{GS} = 10V ; V_{Bus} = 400V$ $I_D = 95A ; R_G = 2.5\Omega$		1270	·	μJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_S	Continuous Source current		$Tc = 25^{\circ}C$		95		Α
	(Body diode)		$Tc = 80^{\circ}C$		70		А
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -95A$	L			1.2	V
dv/dt	Peak Diode Recovery 1					4	V/ns
t_{rr}	Reverse Recovery Time	$I_{S} = -95A$	$T_j = 25^{\circ}C$		600		ns
Q_{rr}	Reverse Recovery Charge	$V_R = 350V$ $di_S/dt = 200A/\mu s$	$T_j = 25^{\circ}C$		34		μС

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

 $I_S \leq \text{- 95A} \qquad \text{di/dt} \leq 200 \text{A/}\mu \text{s} \qquad V_R \leq V_{DSS} \qquad T_j \leq 150 ^{\circ}\text{C}$



Thermal and package characteristics

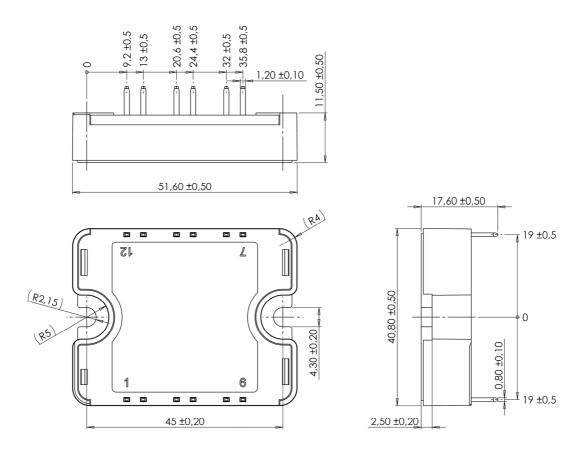
Symbol	Characteristic		Min	Тур	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance					0.27	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150		
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					80	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

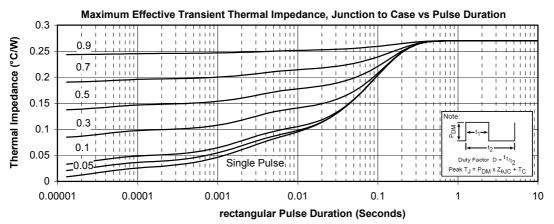
SP1 Package outline (dimensions in mm)

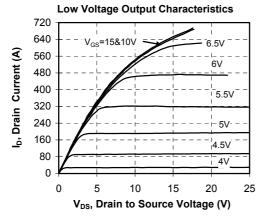


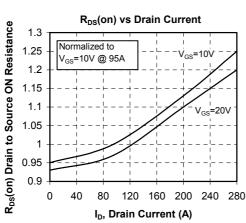
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

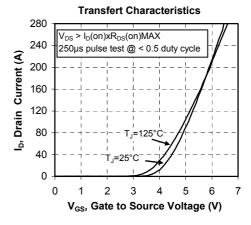


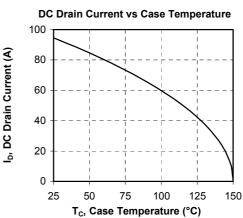
Typical Performance Curve



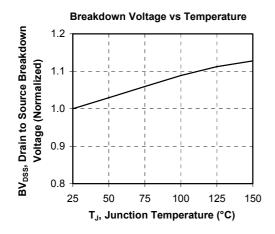


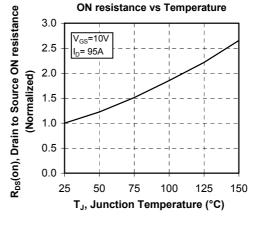


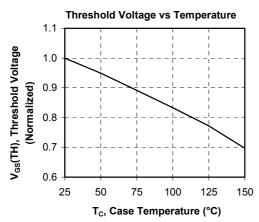


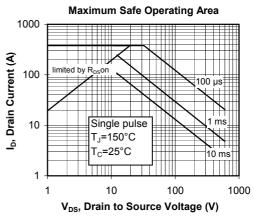


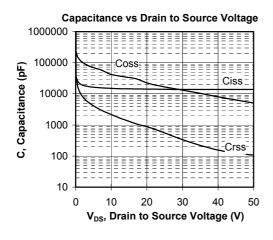


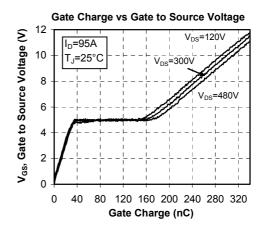




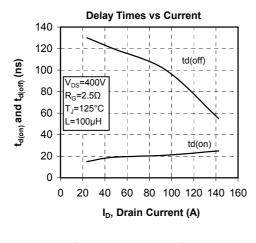


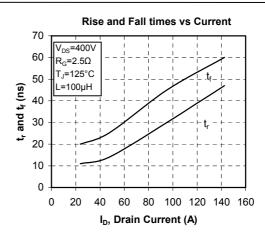


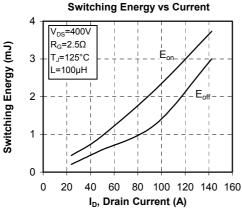


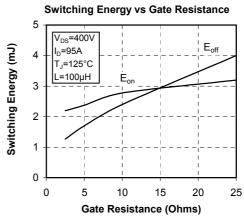


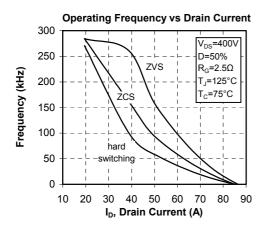


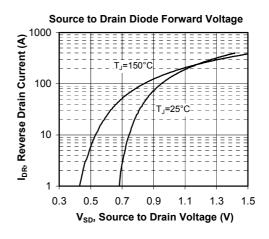












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6 - 7

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